

UNR211x Series (UN211x Series)

Silicon PNP epitaxial planar type

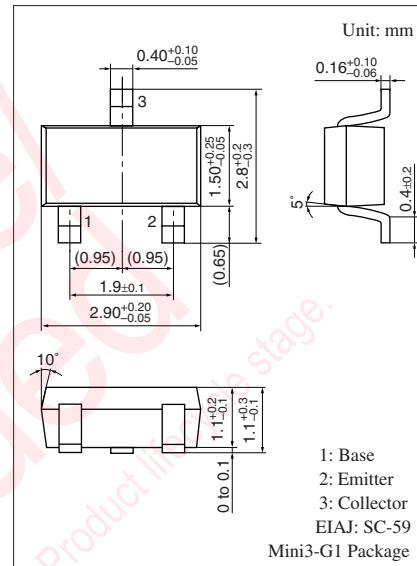
For digital circuits

■ Features

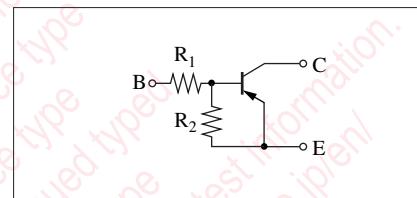
- Costs can be reduced through downsizing of the equipment and reduction of the number of parts
- Mini type package allowing easy automatic insertion through tape packing and magazine packing

■ Resistance by Part Number

	Marking Symbol (R ₁)	(R ₂)
• UNR2110 (UN2110)	6L	47 kΩ
• UNR2111 (UN2111)	6A	10 kΩ
• UNR2112 (UN2112)	6B	22 kΩ
• UNR2113 (UN2113)	6C	47 kΩ
• UNR2114 (UN2114)	6D	10 kΩ
• UNR2115 (UN2115)	6E	10 kΩ
• UNR2116 (UN2116)	6F	4.7 kΩ
• UNR2117 (UN2117)	6H	22 kΩ
• UNR2118 (UN2118)	6I	0.51 kΩ
• UNR2119 (UN2119)	6K	1 kΩ
• UNR211D (UN211D)	6M	47 kΩ
• UNR211E (UN211E)	6N	47 kΩ
• UNR211F (UN211F)	6O	4.7 kΩ
• UNR211H (UN211H)	6P	2.2 kΩ
• UNR211L (UN211L)	6Q	4.7 kΩ
• UNR211M (UN211M)	EI	2.2 kΩ
• UNR211N (UN211N)	EW	4.7 kΩ
• UNR211T (UN211T)	EY	22 kΩ
• UNR211V (UN211V)	FC	2.2 kΩ
• UNR211Z (UN211Z)	FE	4.7 kΩ
		22 kΩ



Internal Connection



■ Absolute Maximum Ratings T_a = 25°C

Parameter	Symbol	Rating	Unit
Collector-base voltage (Emitter open)	V _{CBO}	-50	V
Collector-emitter voltage (Base open)	V _{CEO}	-50	V
Collector current	I _C	-100	mA
Total power dissipation	P _T	200	mW
Junction temperature	T _j	150	°C
Storage temperature	T _{stg}	-55 to +150	°C

Note) The part numbers in the parenthesis show conventional part number.

■ Electrical Characteristics $T_a = 25^\circ\text{C} \pm 3^\circ\text{C}$

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Collector-base voltage (Emitter open)	V_{CBO}	$I_C = -10 \mu\text{A}, I_E = 0$	-50			V
Collector-emitter voltage (Base open)	V_{CEO}	$I_C = -2 \text{ mA}, I_B = 0$	-50			V
Collector-base cutoff current (Emitter open)	I_{CBO}	$V_{\text{CB}} = -50 \text{ V}, I_E = 0$			-0.1	μA
Collector-emitter cutoff current (Base open)	I_{CEO}	$V_{\text{CE}} = -50 \text{ V}, I_B = 0$			-0.5	μA
Emitter-base cutoff current (Collector open)	I_{EBO}	$V_{\text{EB}} = -6 \text{ V}, I_C = 0$		-0.01		mA
UNR2110/2115/2116/2117				-0.1		
UNR2113				-0.2		
UNR2112/2114/211D/ 211E/211M/211N/211T				-0.4		
UNR211Z				-0.5		
UNR2111				-1.0		
UNR211F/211H				-1.5		
UNR2119				-2.0		
UNR2118/211L/211V						
Forward current transfer ratio	h_{FE}	$V_{\text{CE}} = -10 \text{ V}, I_C = -5 \text{ mA}$	6	20		—
UNR211V			20			
UNR2118/211L			30			
UNR2119/211D/211F/211H			35			
UNR2111			60			
UNUNR2112/211E			60	200		
UNR211Z			80			
UNR2113/2114/211M			80	400		
UNR211N/211T			160	460		
UNR2110*/2115*/2116*/2117*						
Collector-emitter saturation voltage	$V_{\text{CE}(\text{sat})}$	$I_C = -10 \text{ mA}, I_B = -0.3 \text{ mA}$			-0.25	V
UNR211V		$I_C = -10 \text{ mA}, I_B = -1.5 \text{ mA}$				
Output voltage high-level	V_{OH}	$V_{\text{CC}} = -5 \text{ V}, V_B = -0.5 \text{ V}, R_L = 1 \text{ k}\Omega$	-4.9			V
Output voltage low-level	V_{OL}	$V_{\text{CC}} = -5 \text{ V}, V_B = -2.5 \text{ V}, R_L = 1 \text{ k}\Omega$			-0.2	V
UNR2113		$V_{\text{CC}} = -5 \text{ V}, V_B = -3.5 \text{ V}, R_L = 1 \text{ k}\Omega$				
UNR211D		$V_{\text{CC}} = -5 \text{ V}, V_B = -10 \text{ V}, R_L = 1 \text{ k}\Omega$				
UNR211E		$V_{\text{CC}} = -5 \text{ V}, V_B = -6 \text{ V}, R_L = 1 \text{ k}\Omega$				
Transition frequency	f_T	$V_{\text{CB}} = -10 \text{ V}, I_E = 1 \text{ mA}, f = 200 \text{ MHz}$		80		MHz
UNR2114/2119/211E 211F/211H		$V_{\text{CB}} = -10 \text{ V}, I_E = 2 \text{ mA}, f = 200 \text{ MHz}$		150		
Input resistance	R_1		-30%	0.51	+30%	k Ω
UNR2118				1.0		
UNR2119				2.2		
UNR211H/211M/211V				4.7		
UNR2116/211F/211L/211N/211Z				10		
UNR2111/2114/2115				22		
UNR2112/2117/211T				47		
UNR2110/2113/211D/211E						

Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

2. *: Rank classification

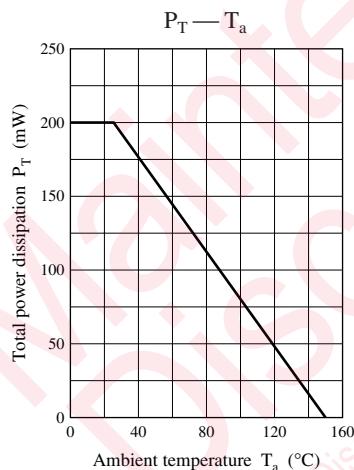
Rank	Q	R	S	No-rank
h_{FE}	160 to 260	210 to 340	290 to 460	160 to 460

■ Electrical Characteristics (continued) $T_a = 25^\circ\text{C} \pm 3^\circ\text{C}$

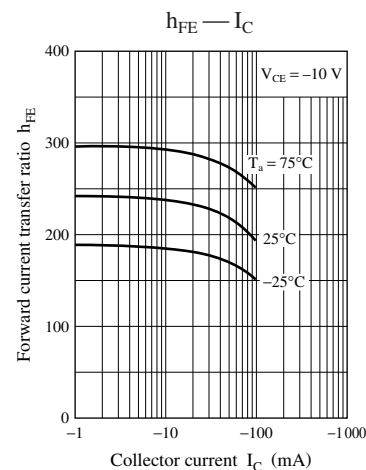
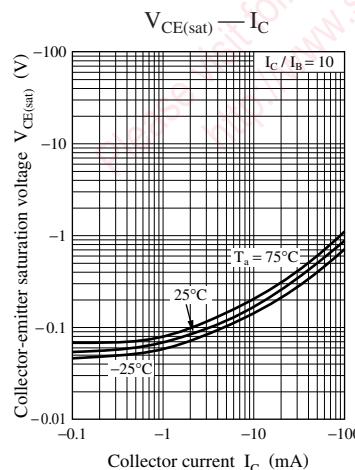
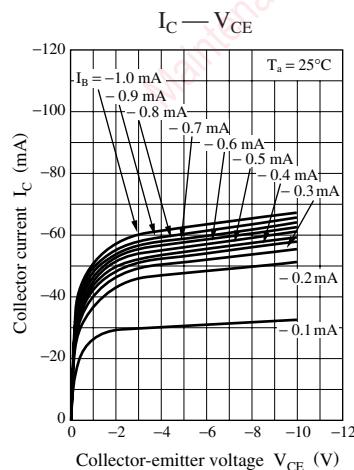
Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Resistance ratio	UNR211M UNR211N UNR2118/2119 UNR211Z UNR2114 UNR211H UNR211T UNR211F UNR211V UNR211/2112/2113/211L UNR211E UNR211D	R_1/R_2		0.047		—
				0.1		
			0.08	0.10	0.12	
				0.21		
			0.17	0.21	0.25	
			0.17	0.22	0.27	
				0.47		
			0.37	0.47	0.57	
				1.0		
			0.8	1.0	1.2	
			1.70	2.14	2.60	
			3.7	4.7	5.7	

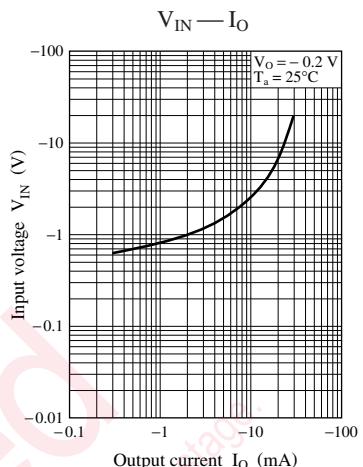
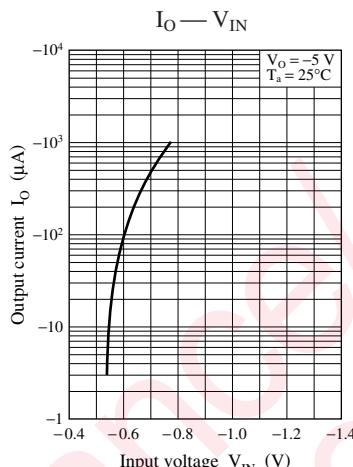
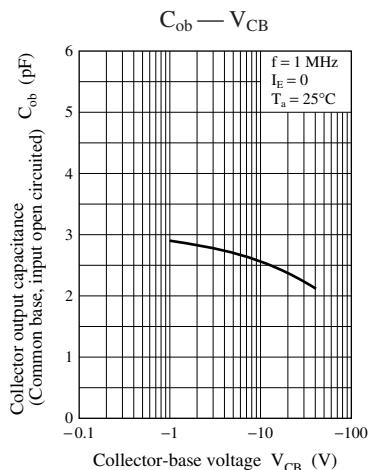
Note) Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

Common characteristics chart

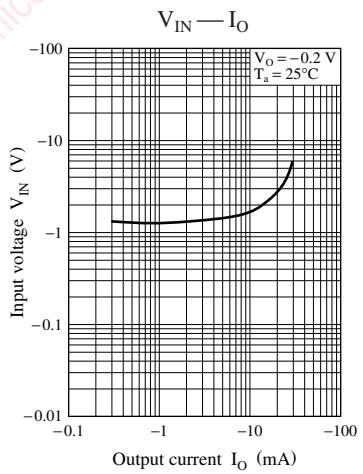
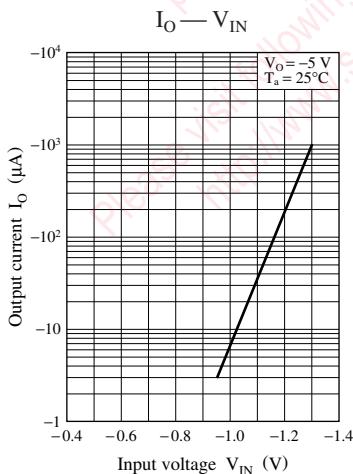
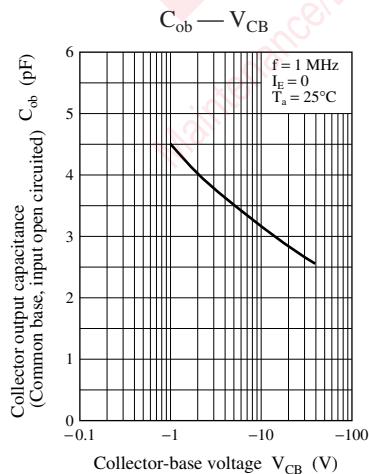
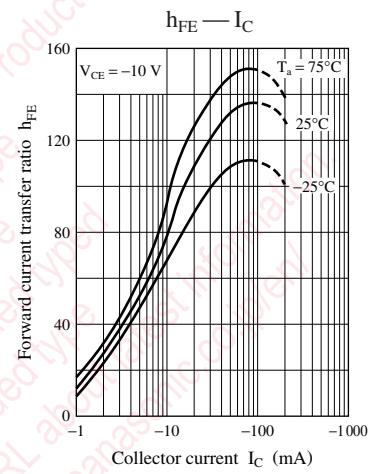
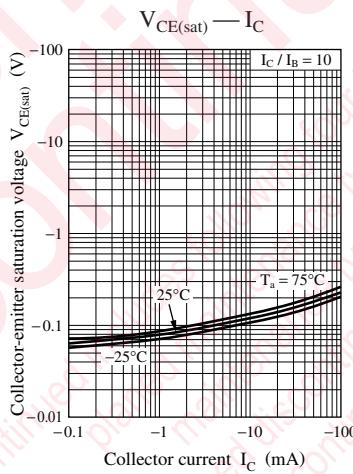
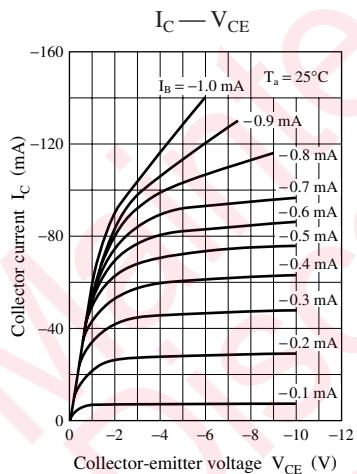


Characteristics charts of UNR2110

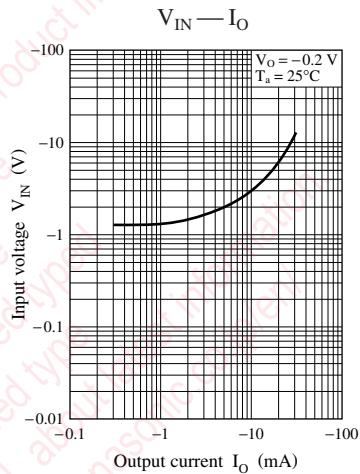
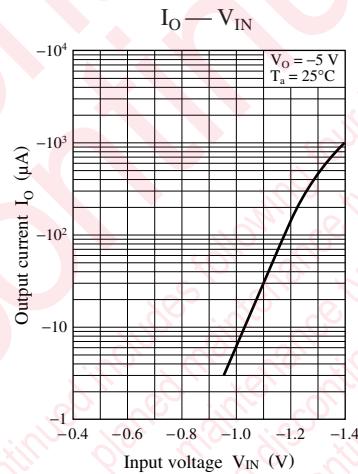
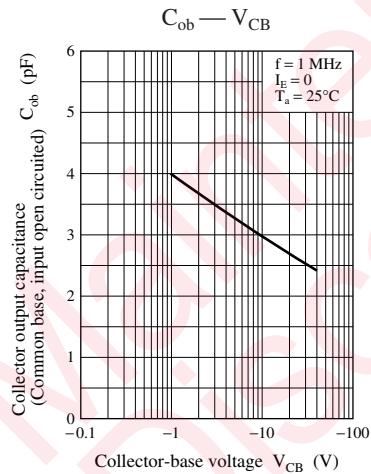
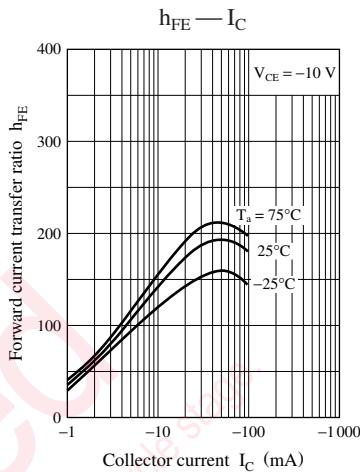
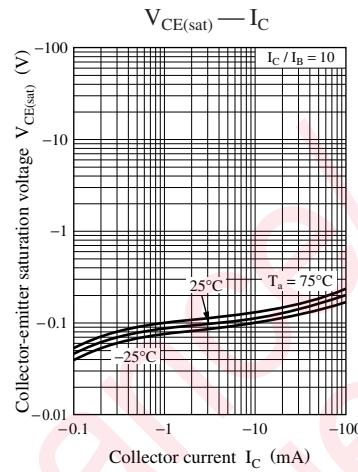
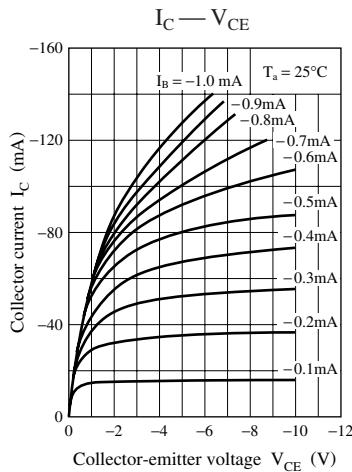




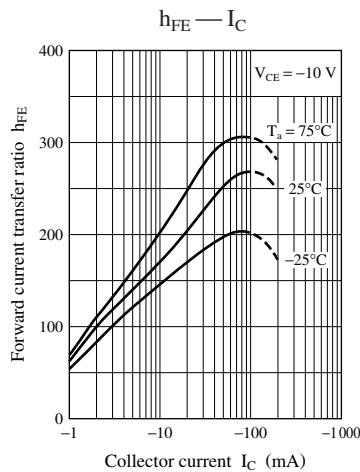
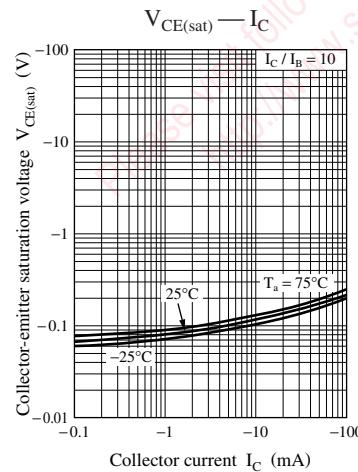
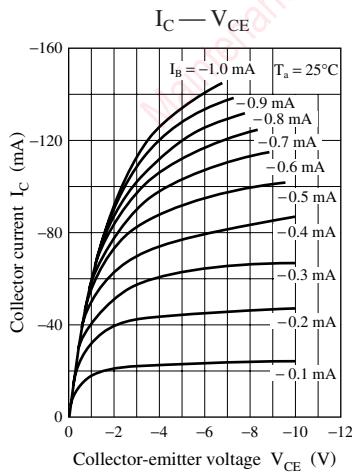
Characteristics charts of UNR2111

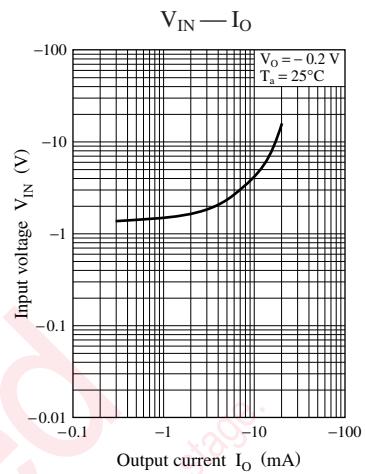
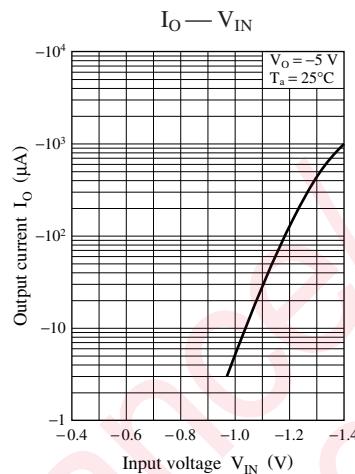
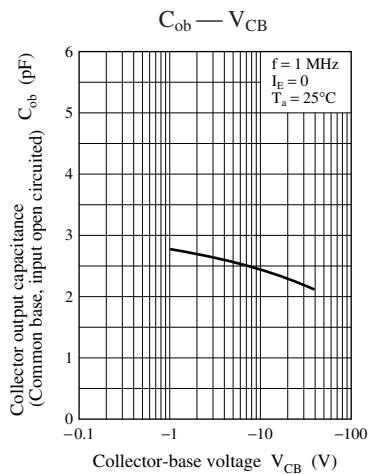


Characteristics charts of UNR2112

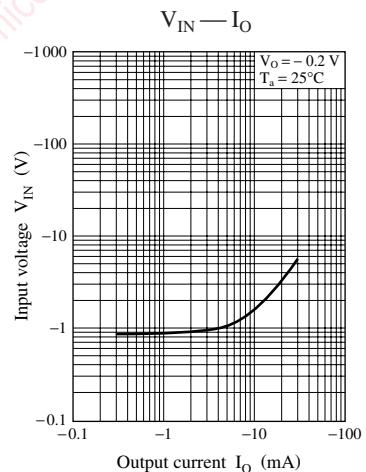
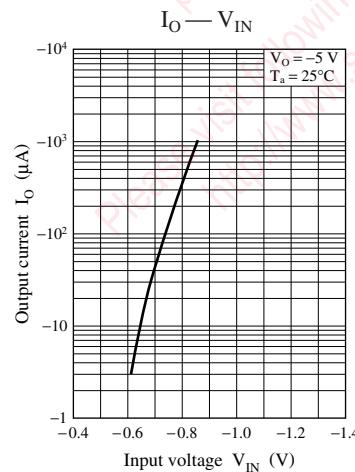
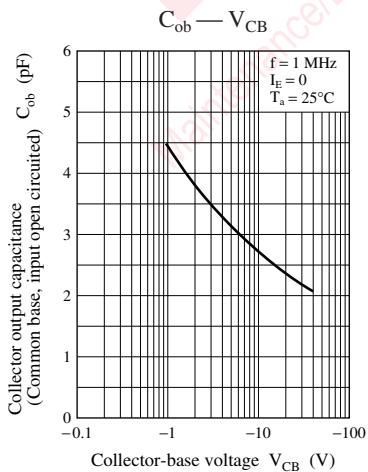
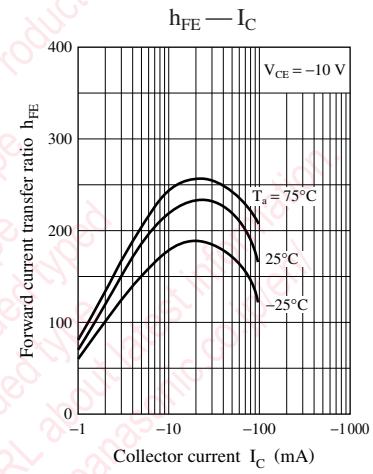
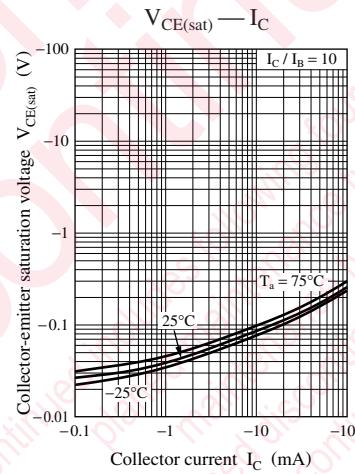
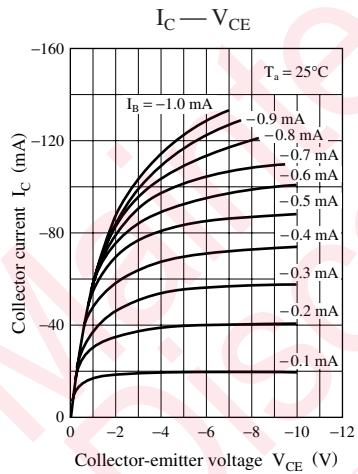


Characteristics charts of UNR2113

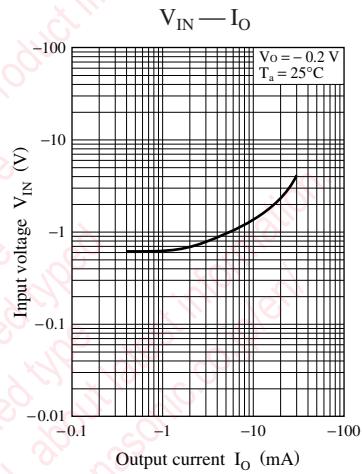
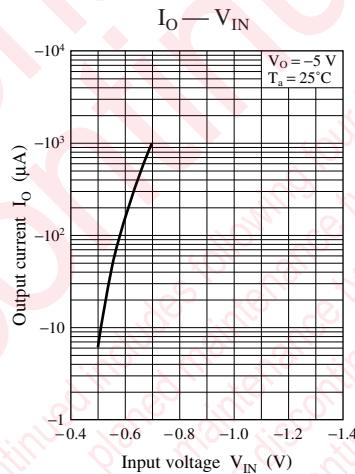
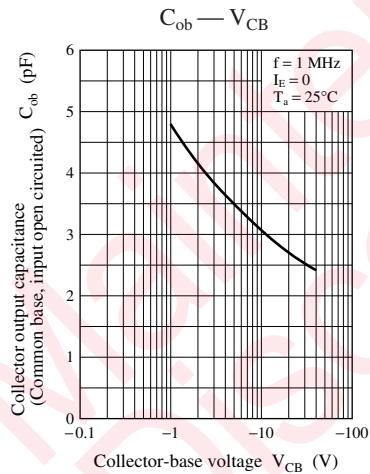
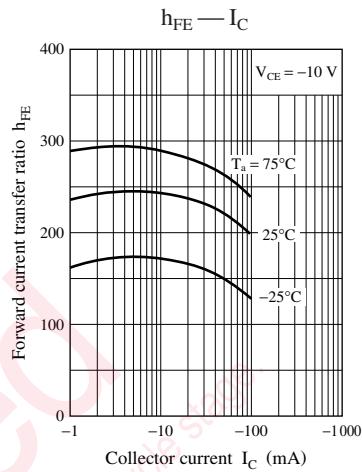
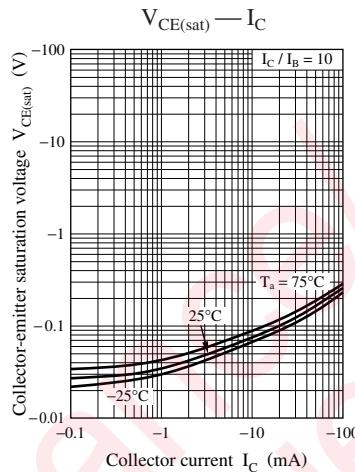
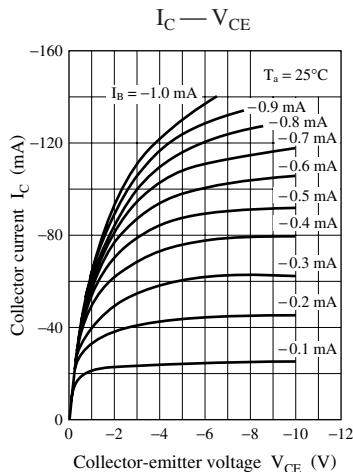




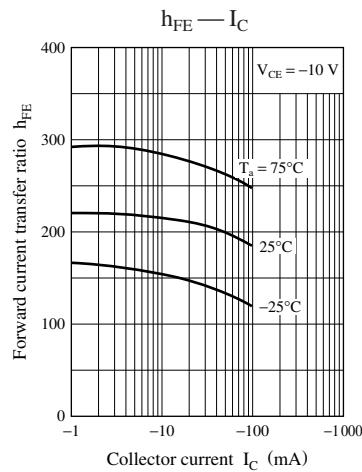
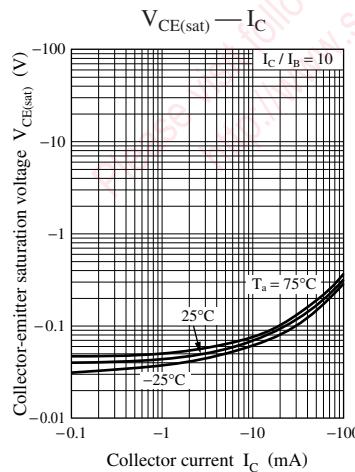
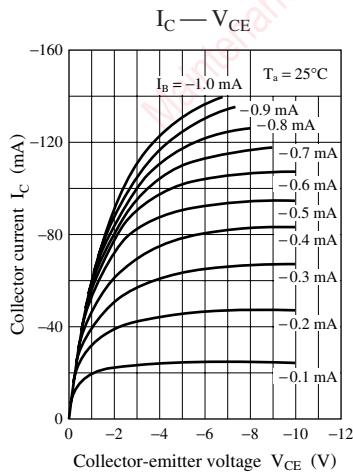
Characteristics charts of UNR2114

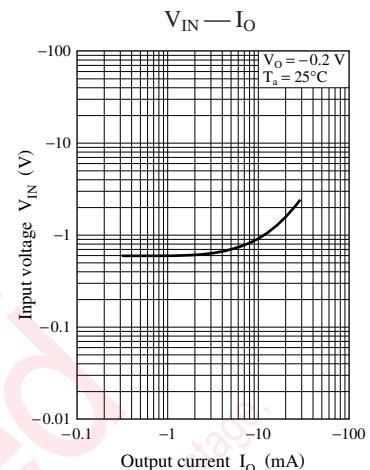
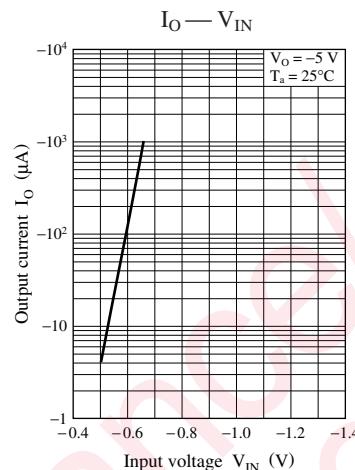
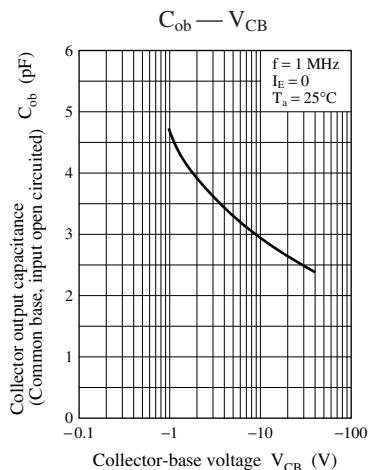


Characteristics charts of UNR2115

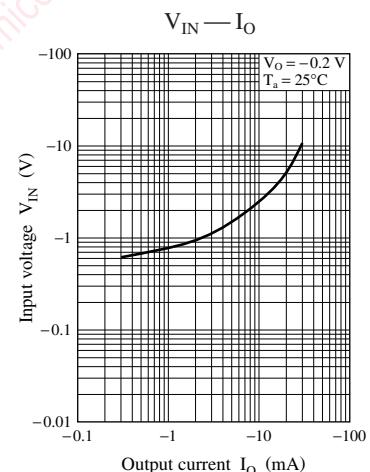
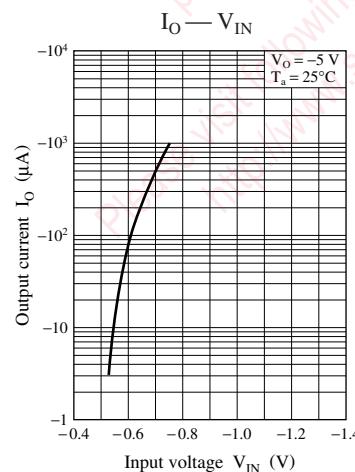
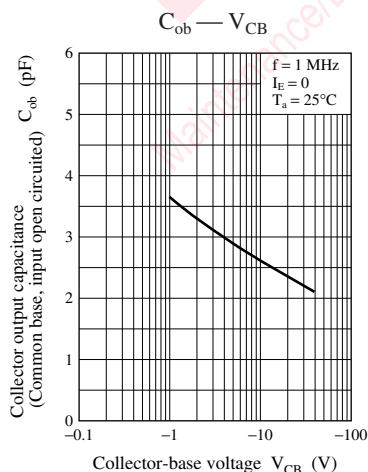
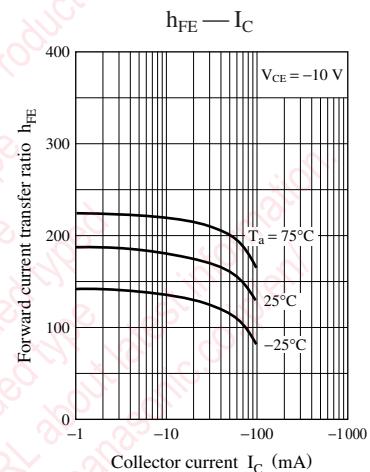
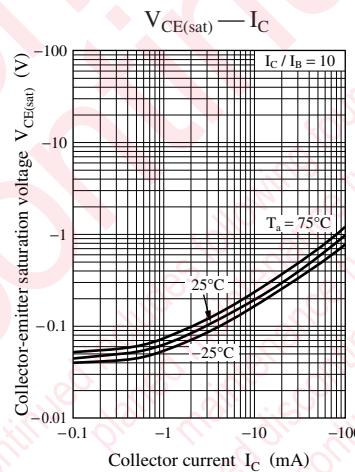
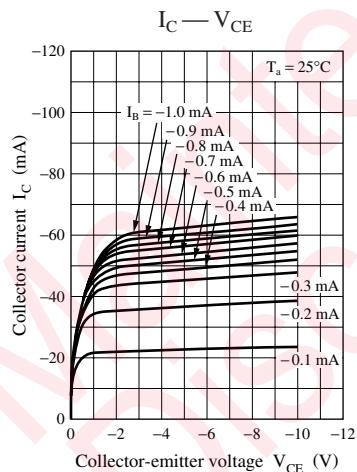


Characteristics charts of UNR2116

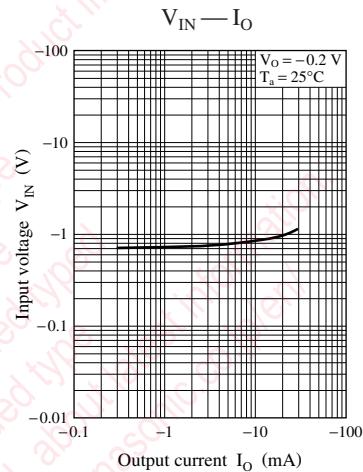
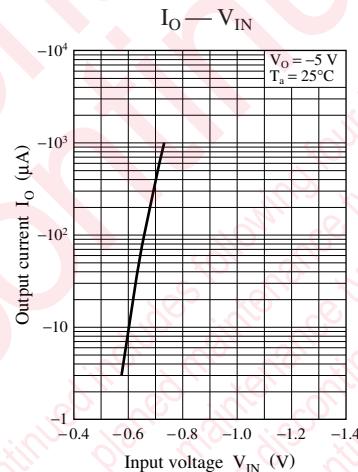
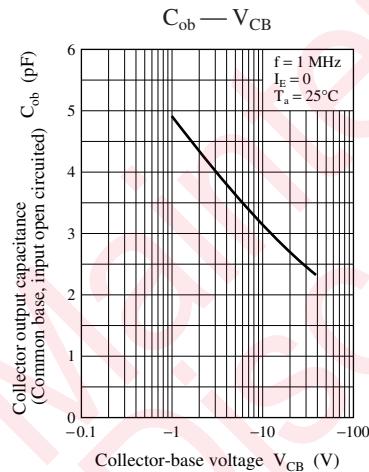
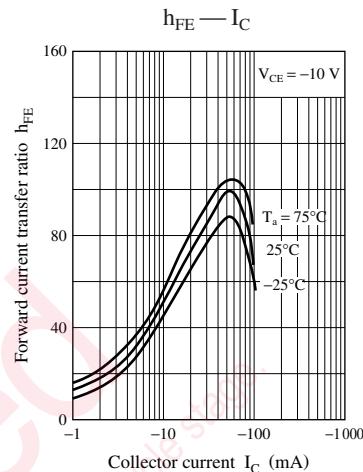
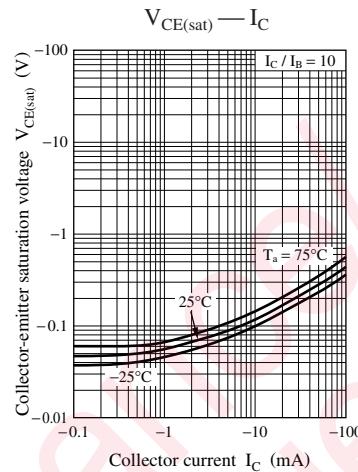
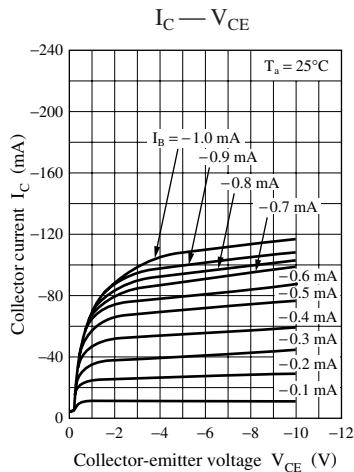




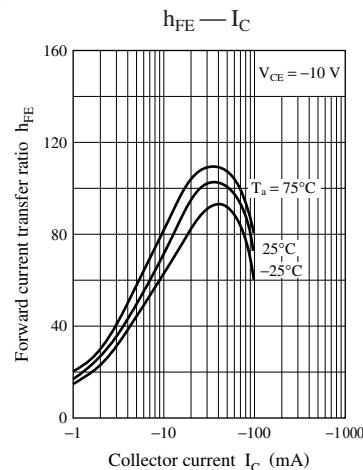
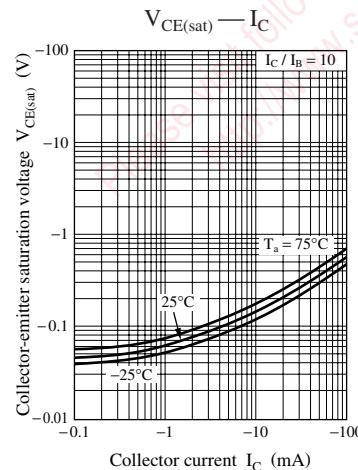
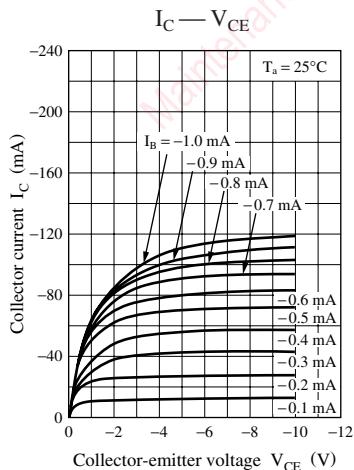
Characteristics charts of UNR2117

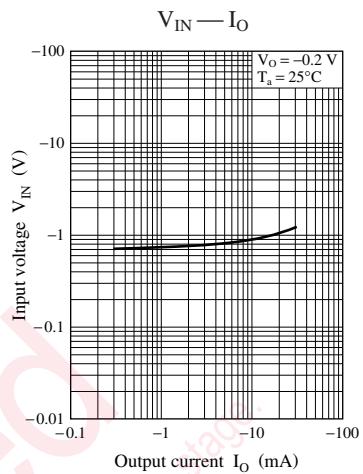
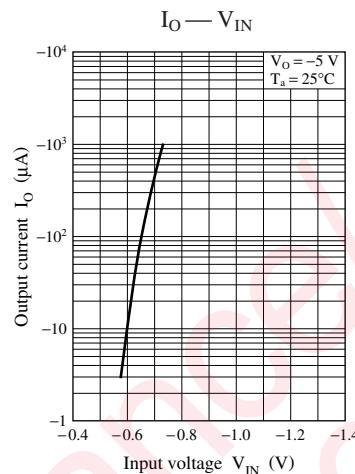
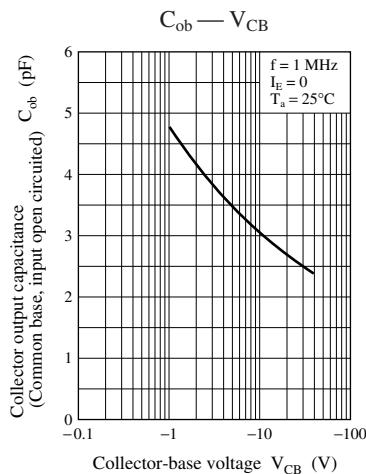


Characteristics charts of UNR2118

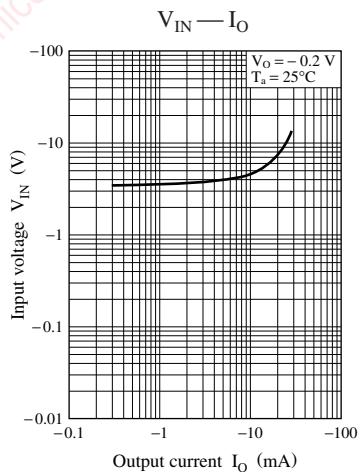
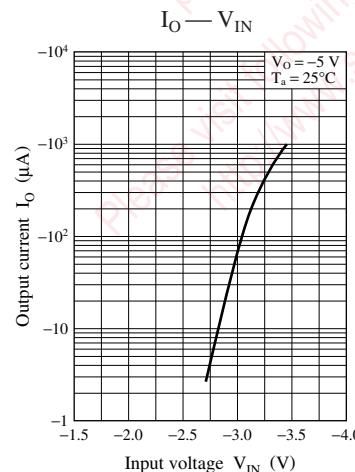
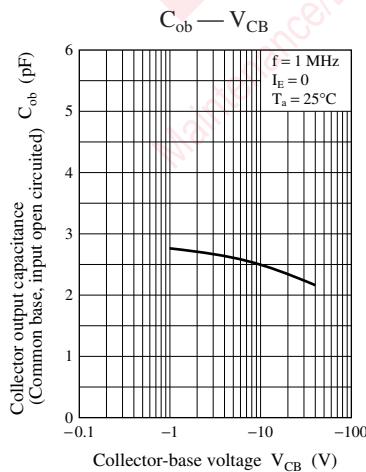
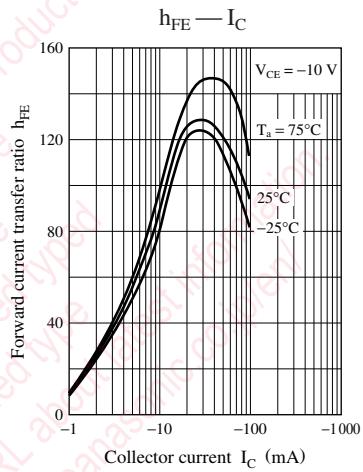
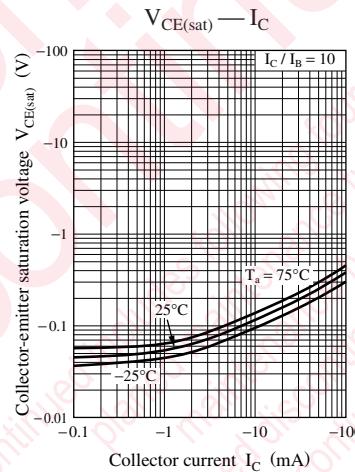
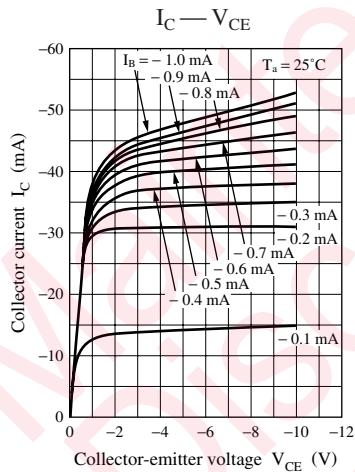


Characteristics charts of UNR2119

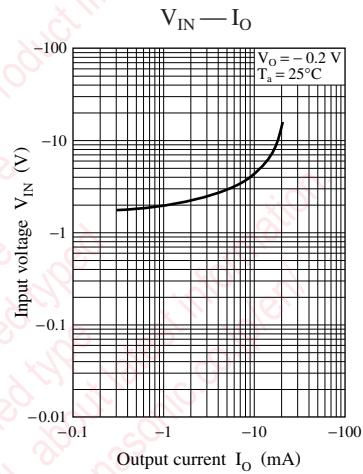
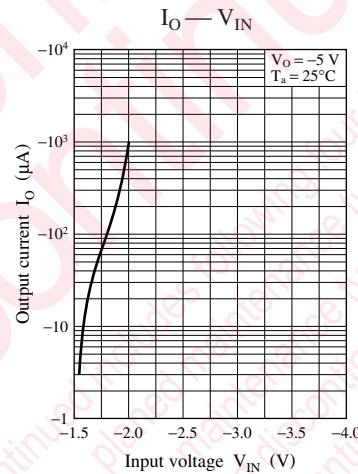
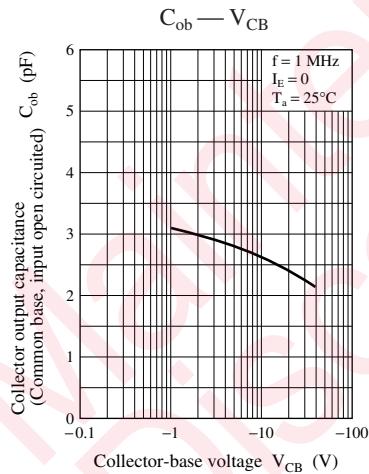
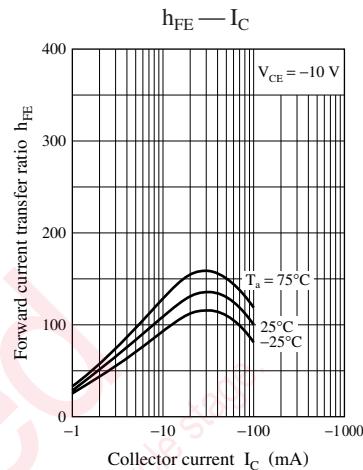
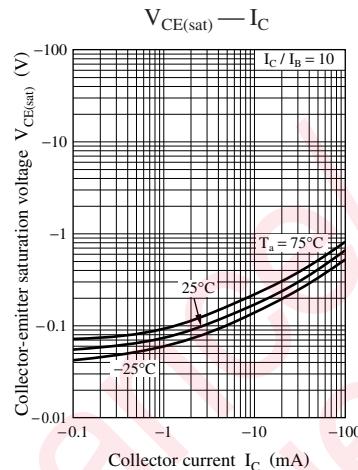
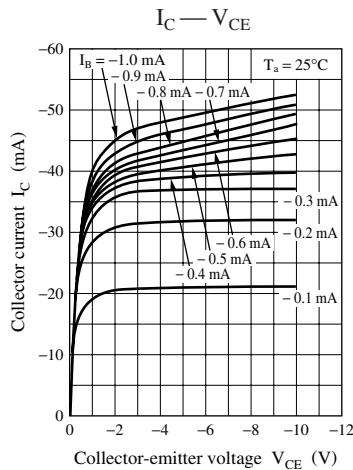




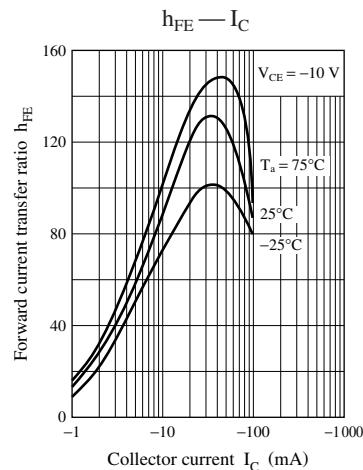
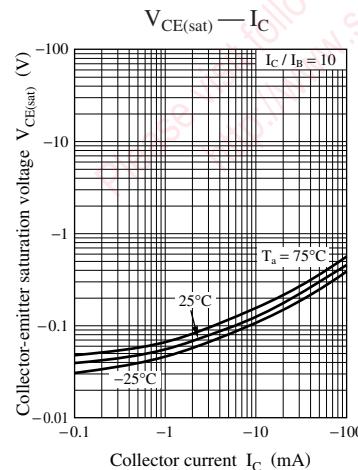
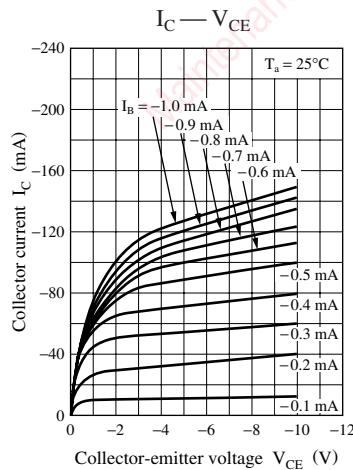
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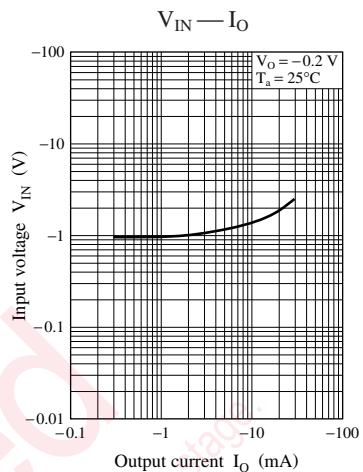
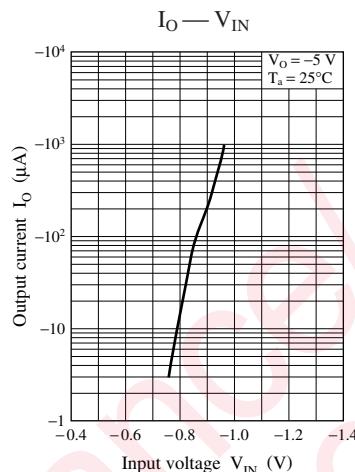
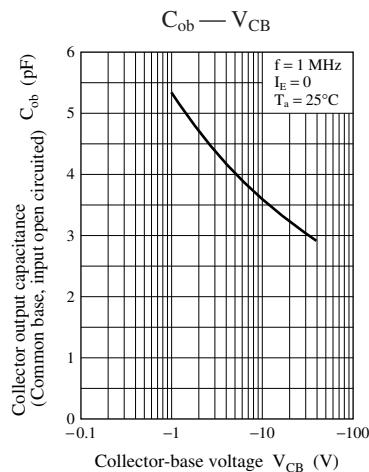


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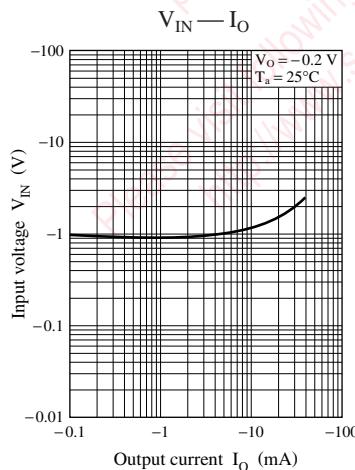
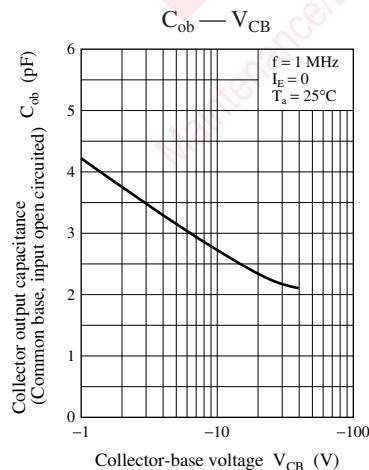
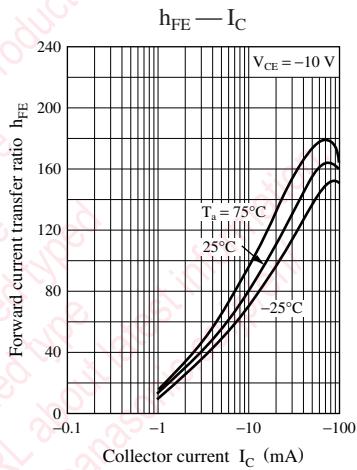
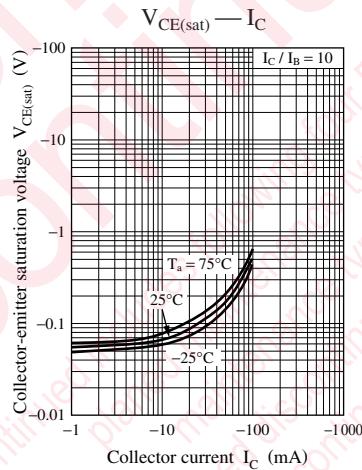
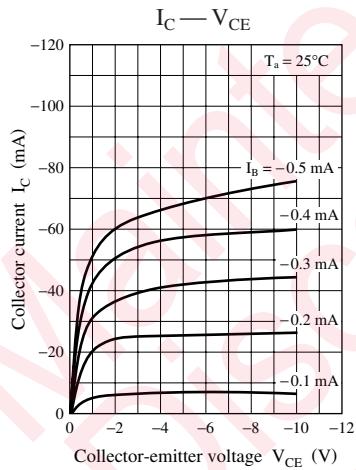


Characteristics charts of UNR211F

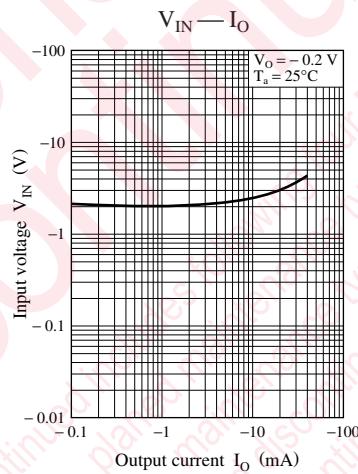
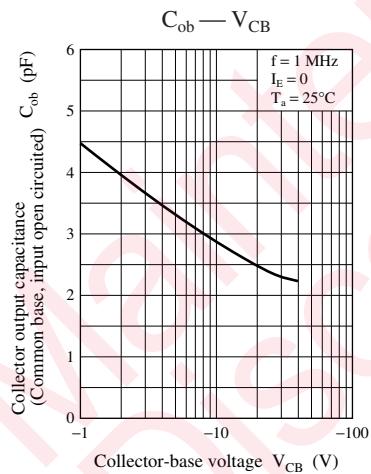
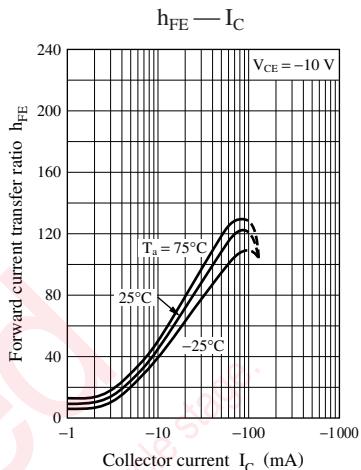
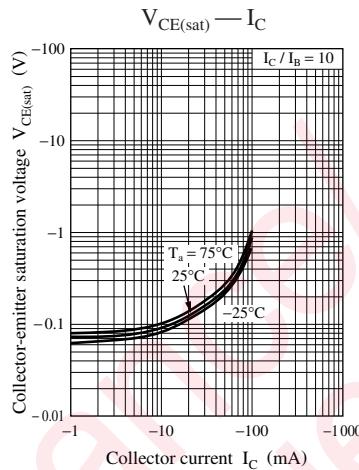
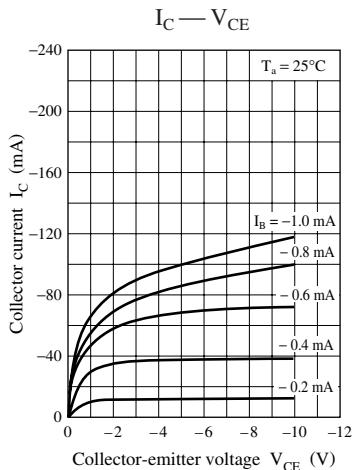




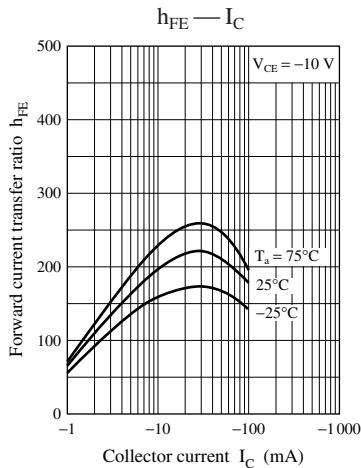
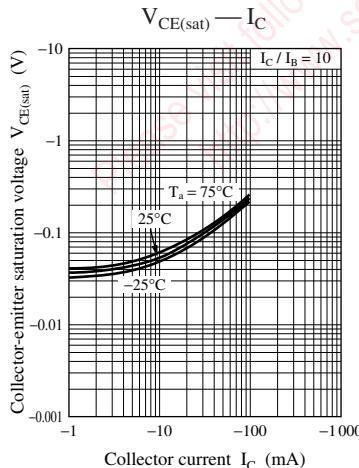
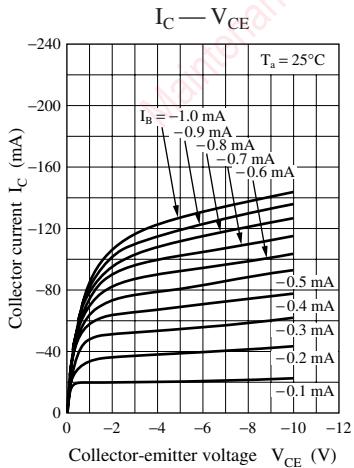
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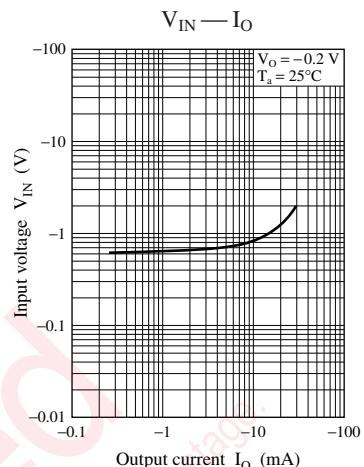
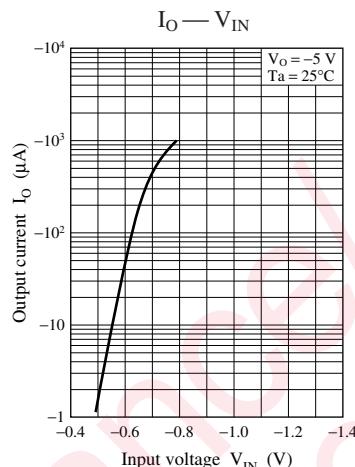
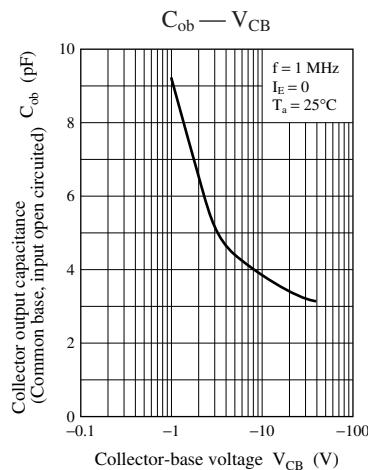


Characteristics charts of UNR211L

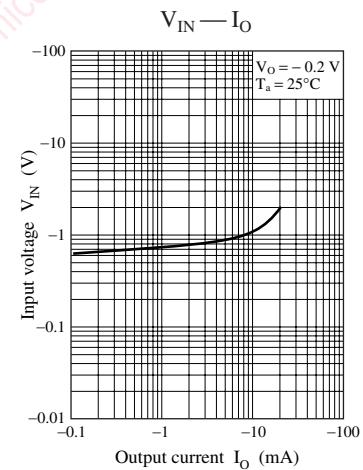
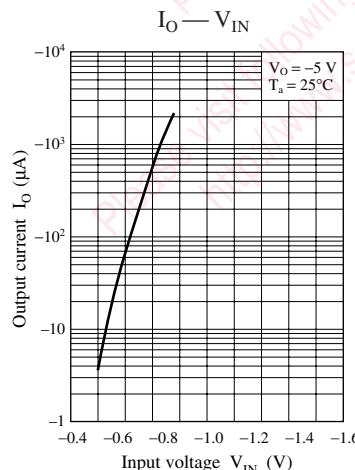
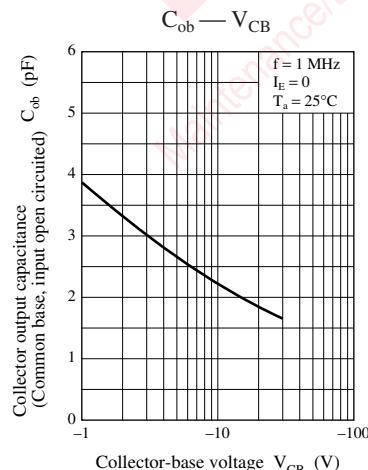
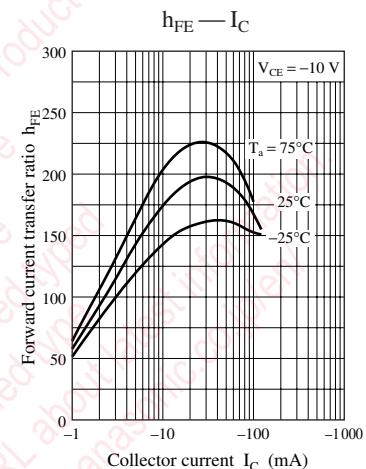
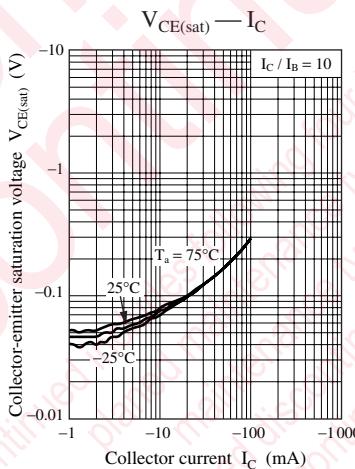
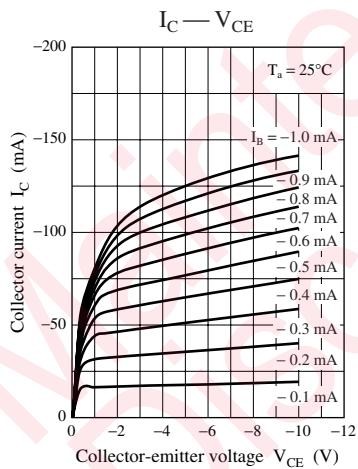


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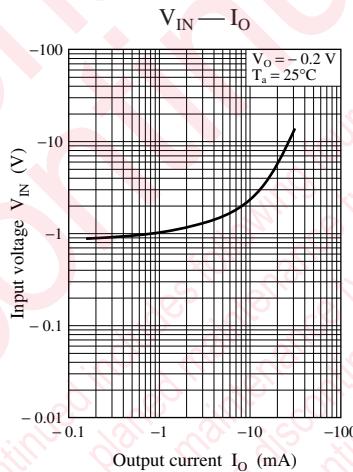
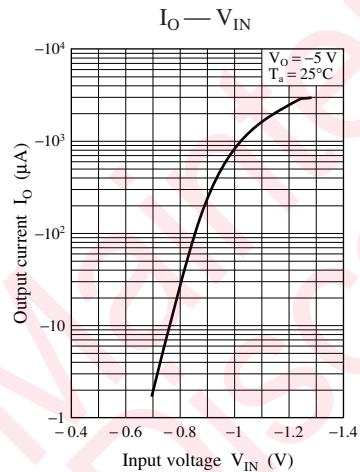
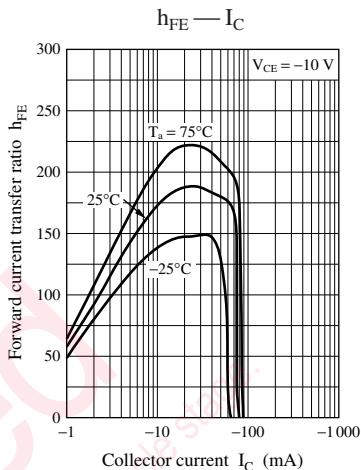
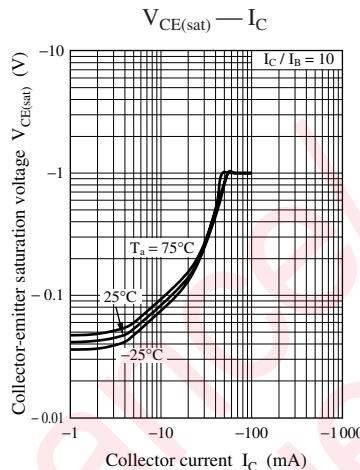
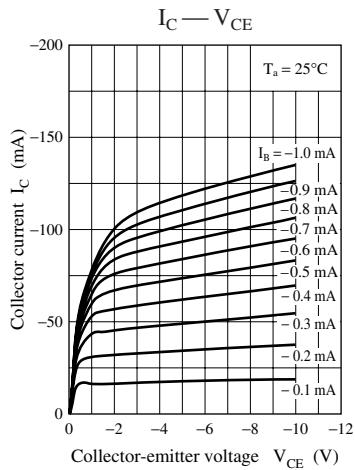




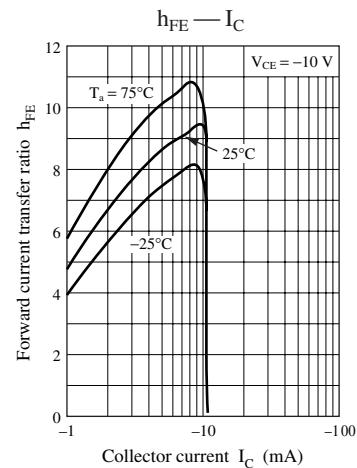
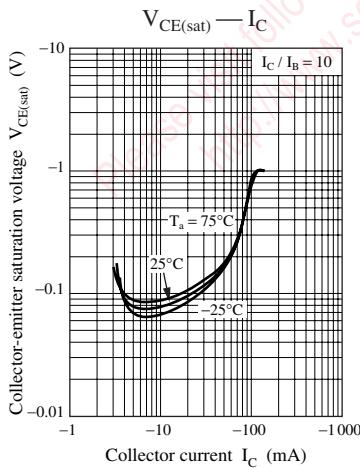
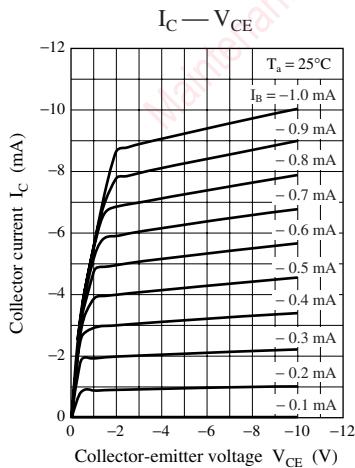
Characteristics charts of UNR211N

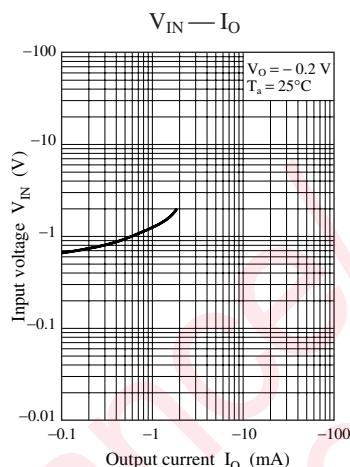
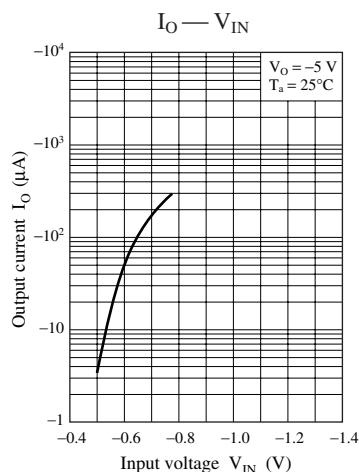


Characteristics charts of UNR211T

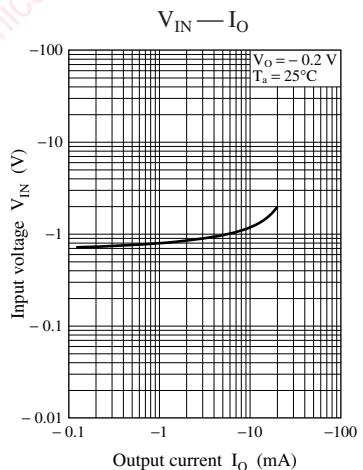
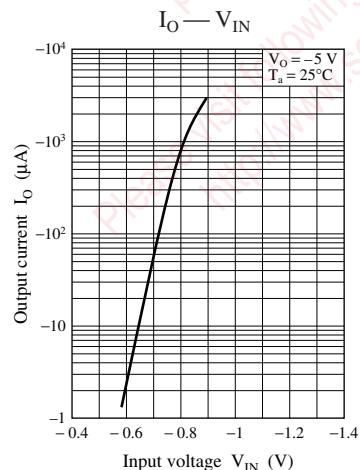
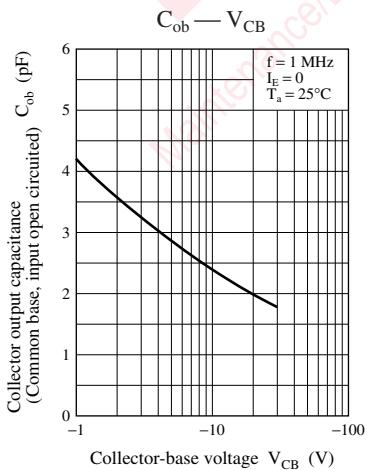
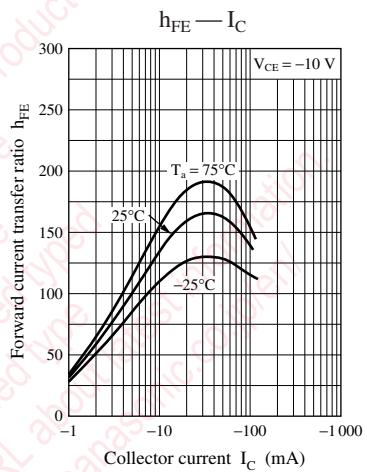
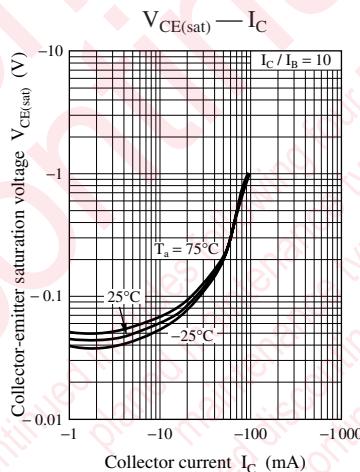
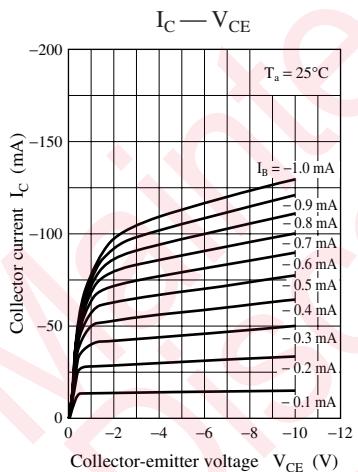


Characteristics charts of UNR211V





Characteristics charts of UNR211Z



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